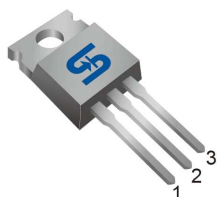
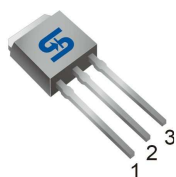




TO-220



TO-251 (IPAK)



TO-252 (DPAK)



Pin Definition:

1. Gate
2. Drain
3. Source

### PRODUCT SUMMARY

V <sub>DS</sub> (V)	R <sub>DS(on)</sub> (Ω)	I <sub>D</sub> (A)
700	6.5 @ V <sub>GS</sub> =10V	1

### General Description

The TSM2N70 N-Channel enhancement mode Power MOSFET is produced by planar stripe DMOS technology. This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance, and withstand high energy pulse in the avalanche and commutation mode. These devices are well suited for high efficiency switch mode power supply, power factor correction, electronic lamp ballast based on half bridge.

### Features

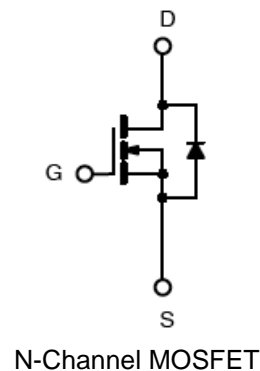
- Low R<sub>DS(ON)</sub> 6.5Ω (Max.)
- Low gate charge typical @ 9.5nC (Typ.)
- Low Crss typical @ 4.5pF (Typ.)
- Fast Switching

### Ordering Information

Part No.	Package	Packing
TSM2N70CZ C0	TO-220	50pcs / Tube
TSM2N70CH C5	TO-251	70pcs / Tube
TSM2N70CH C5G	TO-251	70pcs / Tube
TSM2N70CP RO	TO-252	2.5Kpcs / 13" Reel
TSM2N70CP ROG	TO-252	2.5Kpcs / 13" Reel

Note: "G" denote for Halogen Free Product

### Block Diagram



### Absolute Maximum Rating (T<sub>a</sub> = 25°C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>	700	V
Gate-Source Voltage	V <sub>GS</sub>	±30	V
Continuous Drain Current	I <sub>D</sub>	2	A
Pulsed Drain Current *	I <sub>DM</sub>	8	A
Repetitive avalanche Current	I <sub>AR</sub>	2	A
Single Pulse Avalanche Energy (Note 2)	E <sub>AS</sub>	110	mJ
Maximum Power Dissipation @T <sub>C</sub> = 25°C	P <sub>TOT</sub>	45	W
Operating Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-55 to +150	°C

\* Limited by maximum junction temperature

### Thermal Performance

Parameter	Symbol	Limit	Unit
Thermal Resistance - Junction to Case	R <sub>θJC</sub>	2.78	°C/W
Thermal Resistance - Junction to Ambient	R <sub>θJA</sub>	100	°C/W

Notes: Surface mounted on FR4 board t ≤ 10sec

### Electrical Specifications (Ta = 25°C unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
<b>Static</b>						
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = 1mA$	$BV_{DSS}$	700	--	--	V
Drain-Source On-State Resistance	$V_{GS} = 10V, I_D = 1A$	$R_{DS(ON)}$	--	5.25	6.5	$\Omega$
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 50\mu A$	$V_{GS(TH)}$	2	--	4	V
Zero Gate Voltage Drain Current	$V_{DS} = 700V, V_{GS} = 0V$	$I_{DSS}$	--	--	1	$\mu A$
Gate Body Leakage	$V_{GS} = \pm 20V, V_{DS} = 0V$	$I_{GSS}$	--	--	$\pm 100$	nA
Forward Transconductance	$V_{DS} = 15V, I_D = 0.8A$	$g_{fs}$	--	1.7	--	S
Diode Forward Voltage	$I_S = 1.6A, V_{GS} = 0V$	$V_{SD}$	--	--	1.6	V
<b>Dynamic<sup>b</sup></b>						
Total Gate Charge	$V_{DS} = 480V, I_D = 2A,$ $V_{GS} = 10V$	$Q_g$	--	9.5	13	nC
Gate-Source Charge		$Q_{gs}$	--	1.6	--	
Gate-Drain Charge		$Q_{gd}$	--	4.0	--	
Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$ $f = 1.0MHz$	$C_{iss}$	--	320	--	pF
Output Capacitance		$C_{oss}$	--	35	--	
Reverse Transfer Capacitance		$C_{rss}$	--	4.5	--	
<b>Switching<sup>c</sup></b>						
Turn-On Delay Time	$V_{GS} = 10V, I_D = 0.8A,$ $V_{DD} = 350V, R_G = 4.7\Omega$	$t_{d(on)}$	--	18.4	--	nS
Turn-On Rise Time		$t_r$	--	35	--	
Turn-Off Delay Time		$t_{d(off)}$	--	32	--	
Turn-Off Fall Time		$t_f$	--	34	--	
Reverse Recovery Time	$V_{GS} = 0V, I_S = 1.3A,$	$t_{rr}$	--	474.2	--	nS
Reverse Recovery Charge	$V_{DD} = 25V$	$Q_{rr}$	--	2067.8	--	$\mu C$
Reverse Recovery Current	$di_f/dt = 100A/\mu s$	$I_{RRM}$	--	5.16	--	A

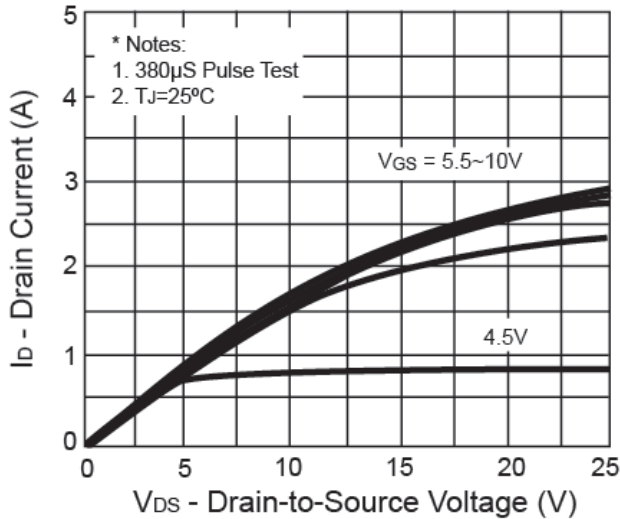
#### Notes:

1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature
2.  $V_{DD} = 50V, I_{AS} = 2A, L = 56mH, R_G = 25\Omega$
3. Pulse test: pulse width  $\leq 300\mu s$ , duty cycle  $\leq 1.5\%$
4. Essentially Independent of Operating Temperature
5. For design reference only, not subject to production testing.
6. Switching time is essentially independent of operating temperature.

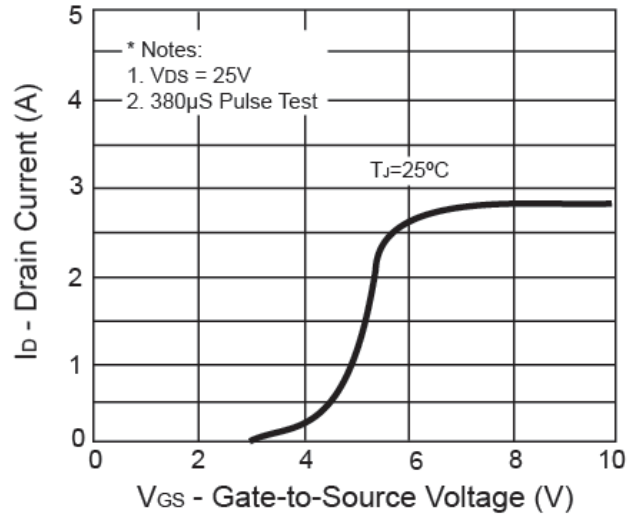


**Electrical Characteristics Curve** (Ta = 25°C, unless otherwise noted)

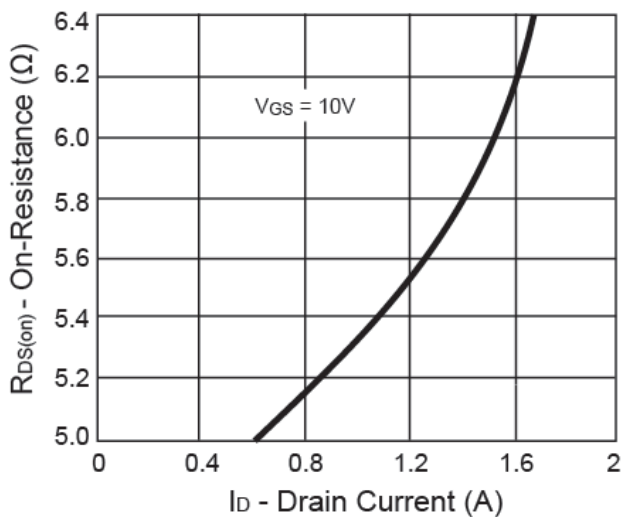
**Output Characteristics**



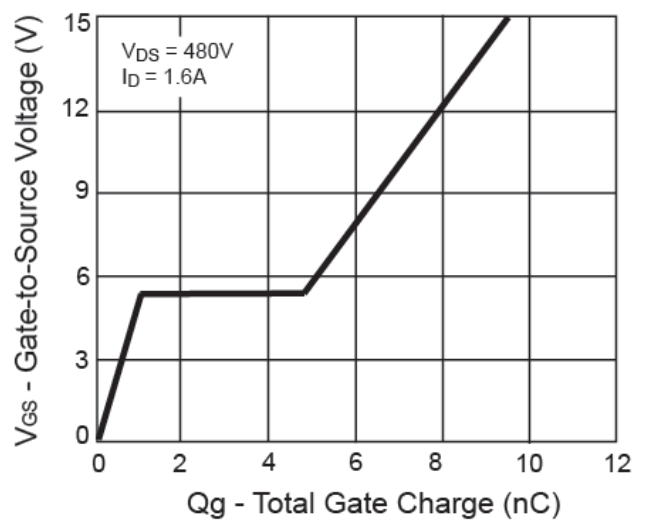
**Transfer Characteristics**



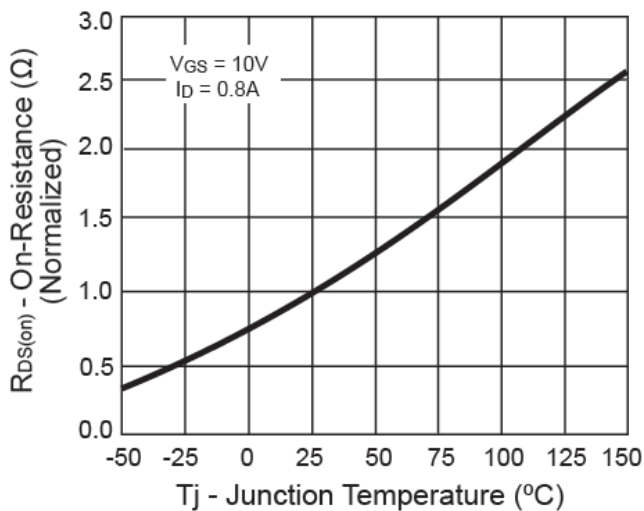
**On-Resistance vs. Drain Current**



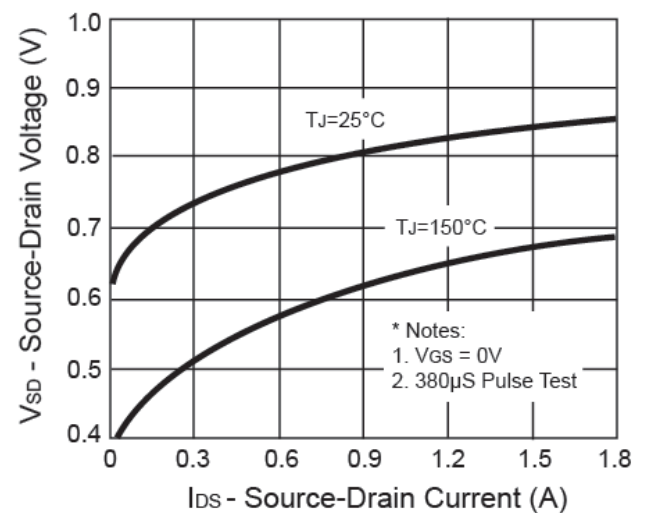
**Gate Charge**



**On-Resistance vs. Junction Temperature**

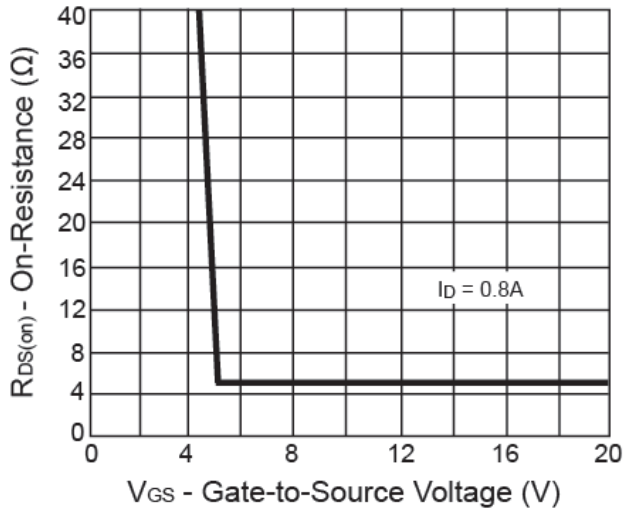


**Source-Drain Diode Forward Voltage**

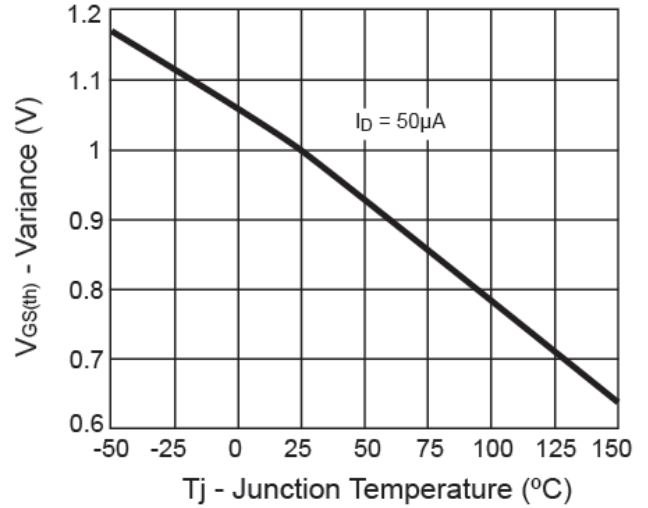


**Electrical Characteristics Curve** (Ta = 25°C, unless otherwise noted)

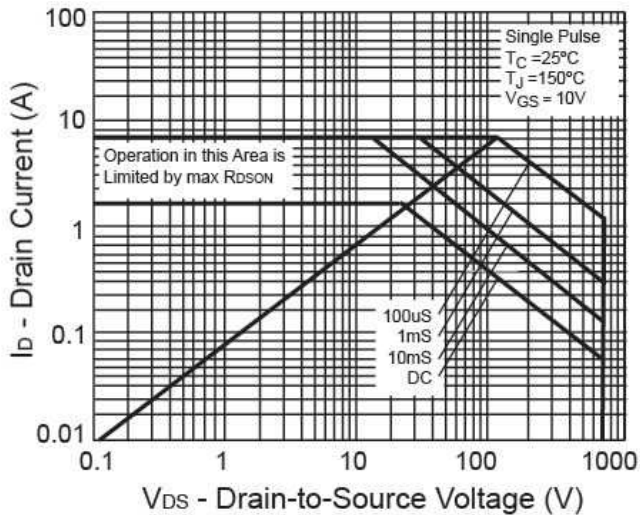
**On-Resistance vs. Gate-Source Voltage**



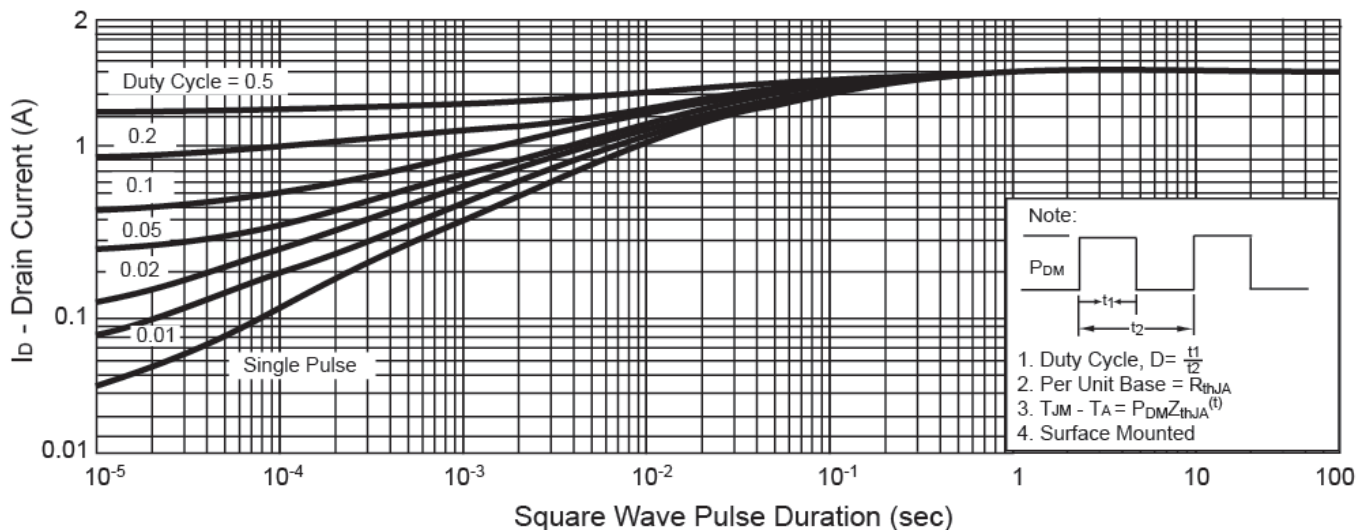
**Threshold Voltage**



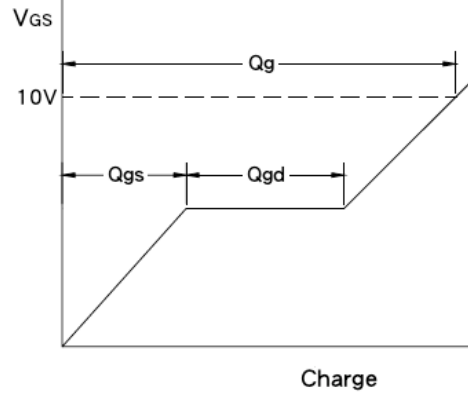
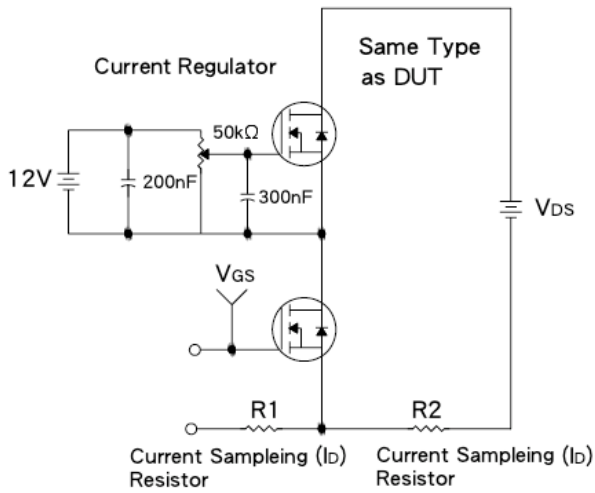
**Maximum Safe Operating Area**



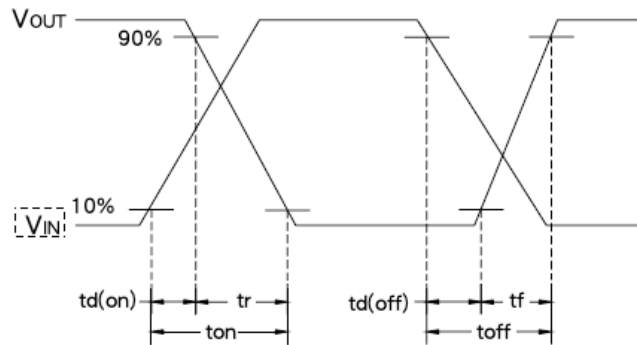
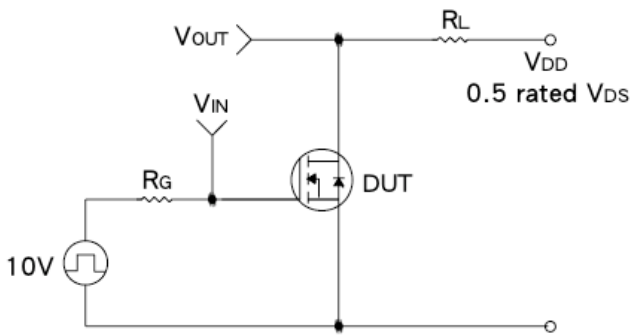
**Normalized Thermal Transient Impedance, Junction-to-Ambient**



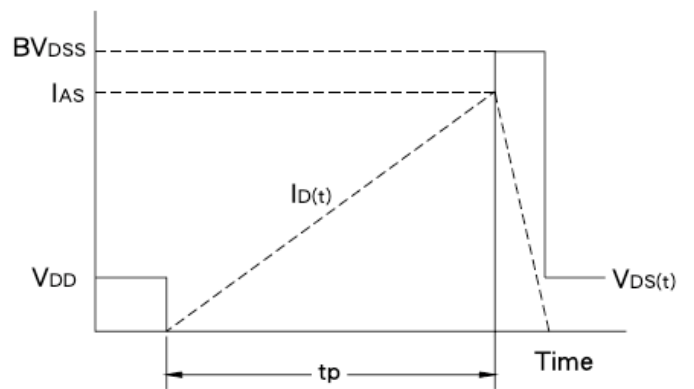
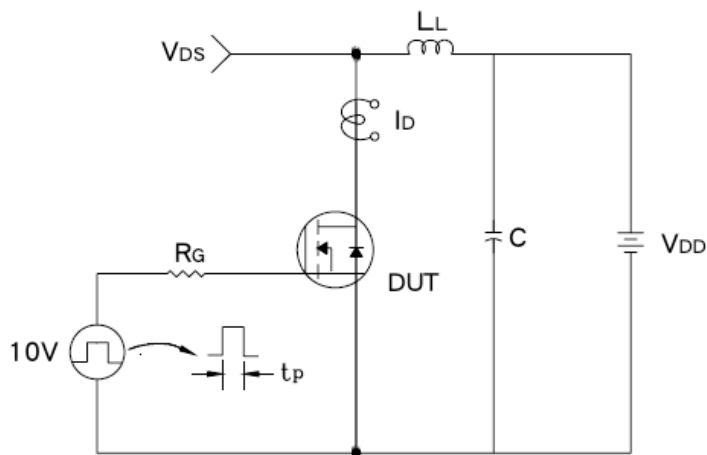
### Gate Charge Test Circuit & Waveform



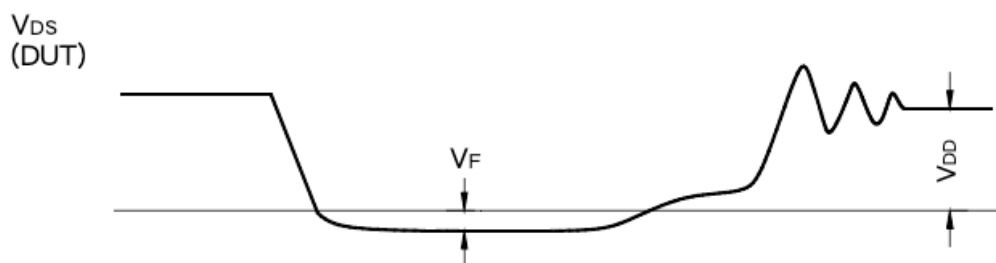
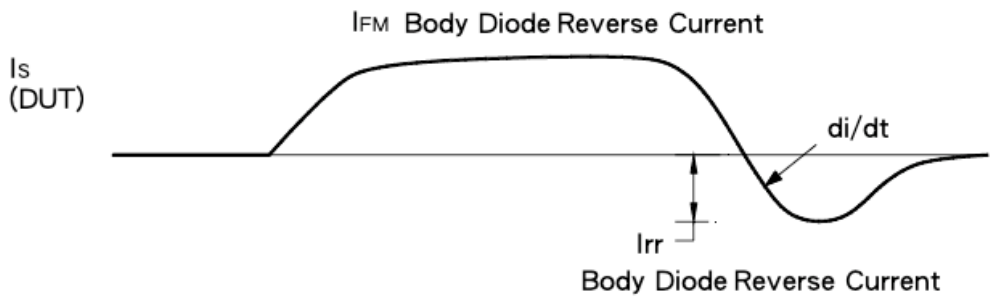
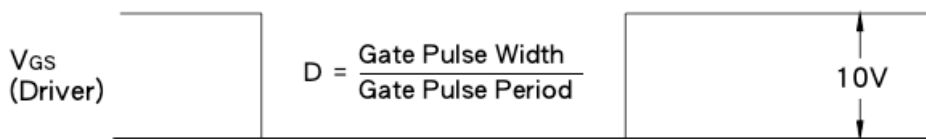
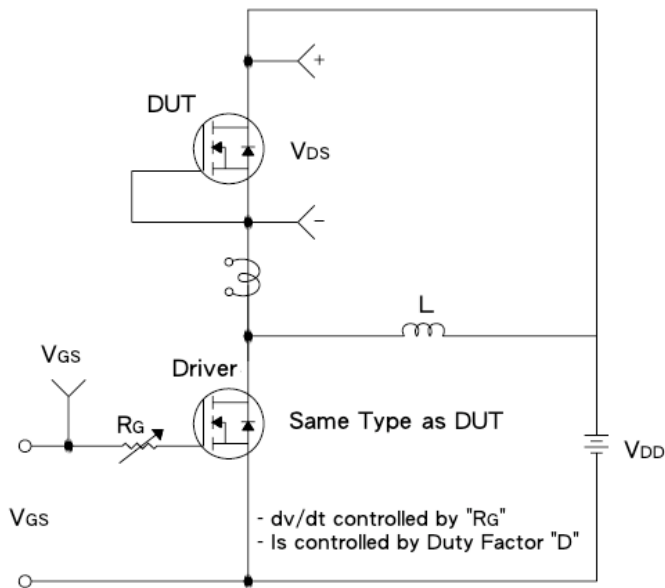
### Resistive Switching Test Circuit & Waveform



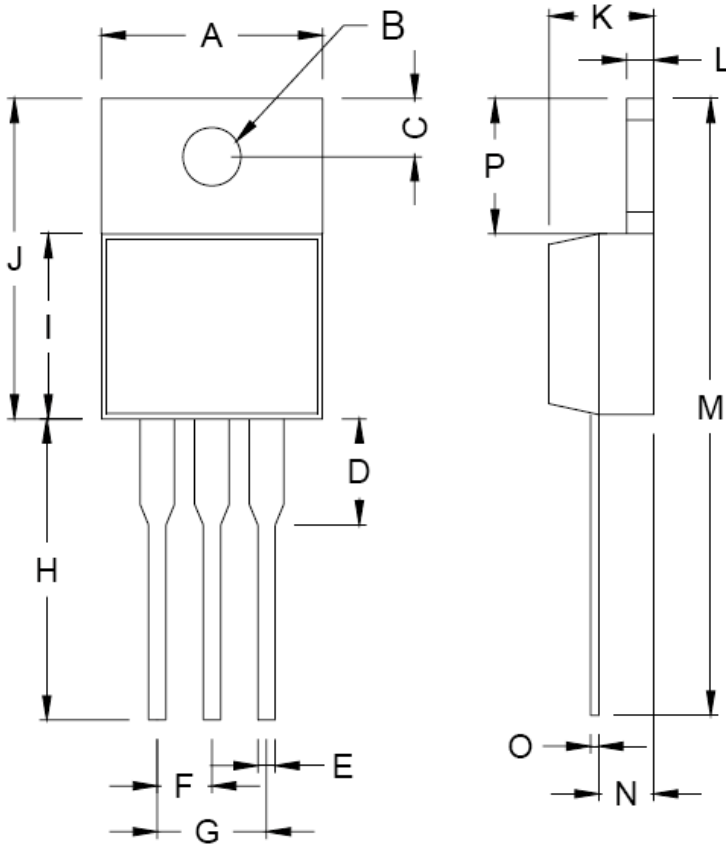
### EAS Test Circuit & Waveform



**Diode Reverse Recovery Time Test Circuit & Waveform**

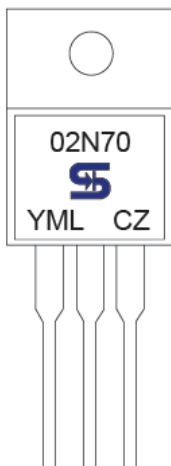


### TO-220 Mechanical Drawing



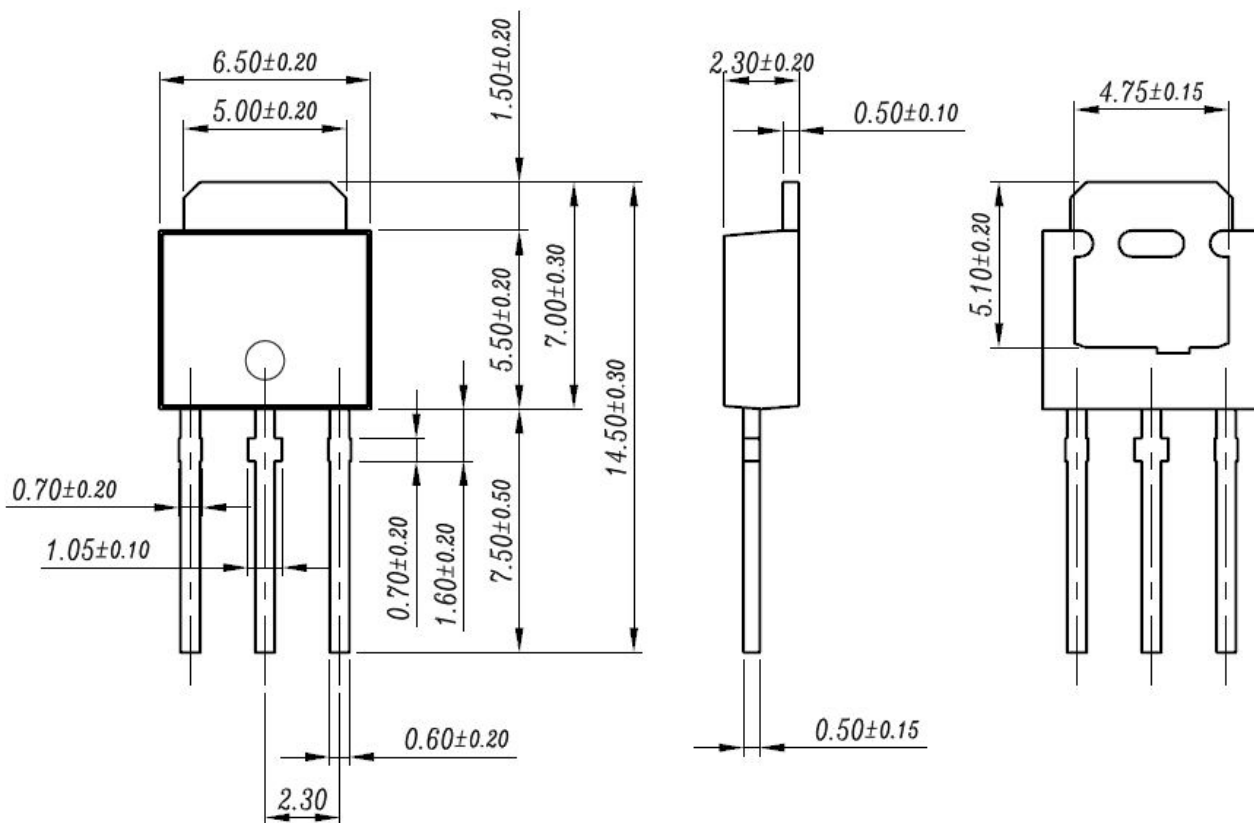
DIM	TO-220 DIMENSION			
	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	10.000	10.500	0.394	0.413
B	3.740	3.910	0.147	0.154
C	2.440	2.940	0.096	0.116
D	-	6.350	-	0.250
E	0.381	1.106	0.015	0.040
F	2.345	2.715	0.092	0.058
G	4.690	5.430	0.092	0.107
H	12.700	14.732	0.500	0.581
J	14.224	16.510	0.560	0.650
K	3.556	4.826	0.140	0.190
L	0.508	1.397	0.020	0.055
M	27.700	29.620	1.060	1.230
N	2.032	2.921	0.080	0.115
O	0.255	0.610	0.010	0.024
P	5.842	6.858	0.230	0.270

### Marking Diagram



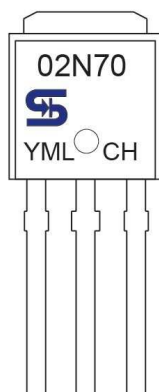
- Y** = Year Code
- M** = Month Code  
(**A**=Jan, **B**=Feb, **C**=Mar, **D**=Apr, **E**=May, **F**=Jun, **G**=Jul, **H**=Aug, **I**=Sep, **J**=Oct, **K**=Nov, **L**=Dec)
- L** = Lot Code

**TO-251 Mechanical Drawing**



Unit: Millimeters

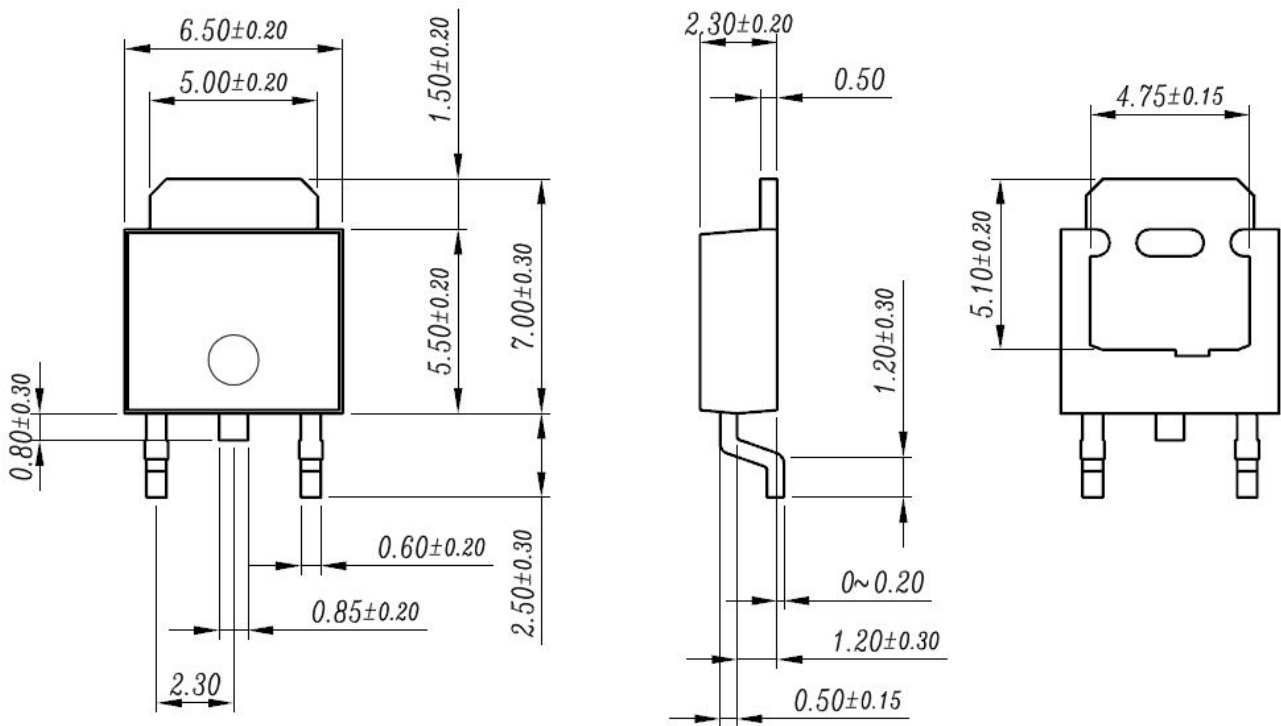
**Marking Diagram**



- Y** = Year Code
- M** = Month Code
  - (A=Jan, B=Feb, C=Mar, D=Apl, E=May, F=Jun, G=Jul, H=Aug, I=Sep, J=Oct, K=Nov, L=Dec)
  - = Month Code for Halogen Free Product
  - (O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)
- L** = Lot Code

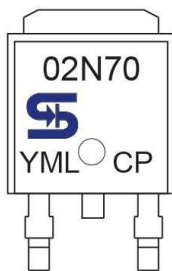


**TO-252 Mechanical Drawing**



Unit: Millimeters

**Marking Diagram**



- Y** = Year Code
- M** = Month Code  
(A=Jan, B=Feb, C=Mar, D=Apl, E=May, F=Jun, G=Jul, H=Aug, I=Sep, J=Oct, K=Nov, L=Dec)
- YML** = Month Code for Halogen Free Product  
(O=Jan, P=Feb, Q=Mar, R=Apl, S=May, T=Jun, U=Jul, V=Aug, W=Sep, X=Oct, Y=Nov, Z=Dec)
- L** = Lot Code

### Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.